

Study on radiation-induced degradation of VUV sensitivity in multi-pixel photon counters tested in liquid xenon

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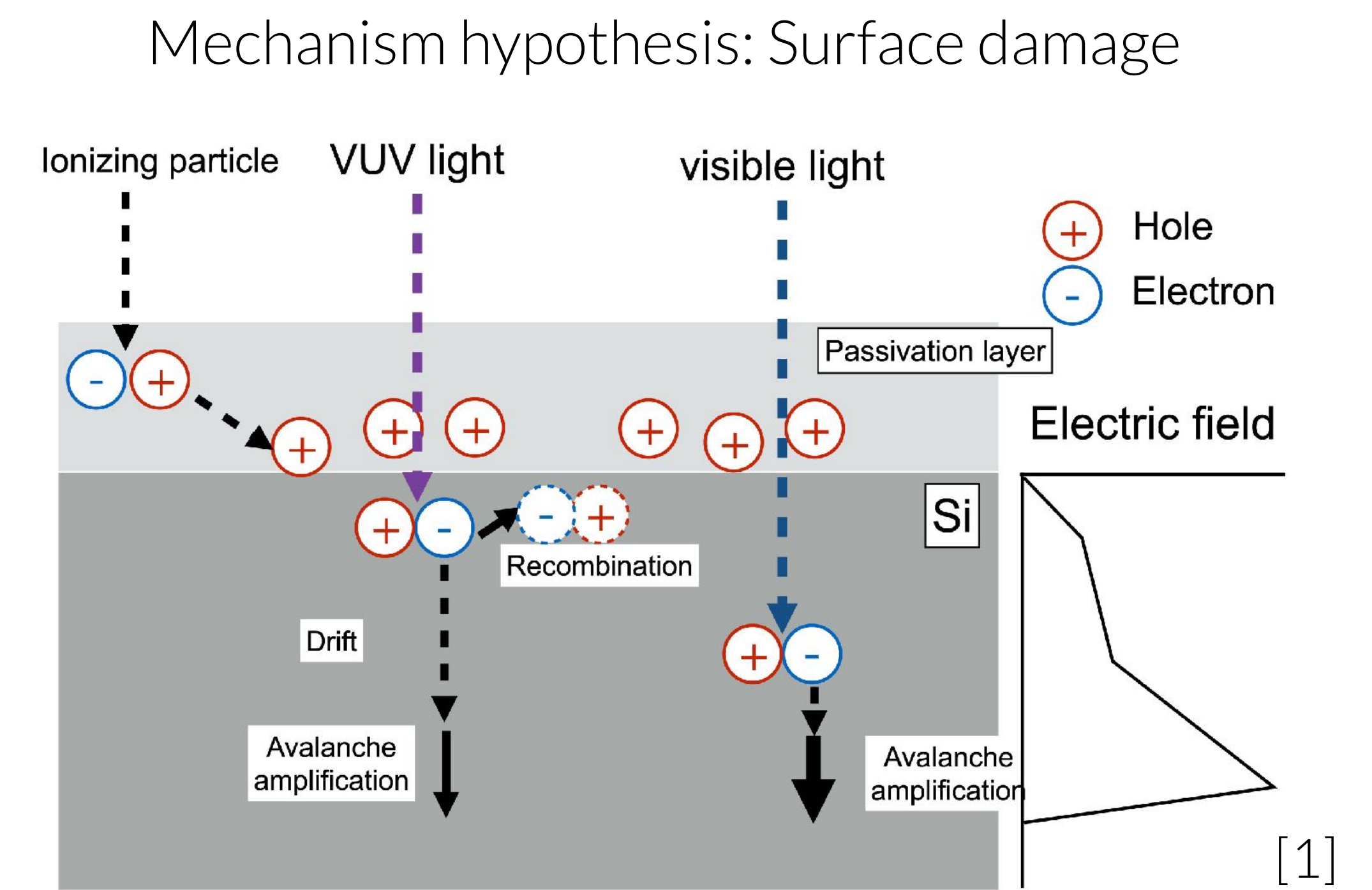
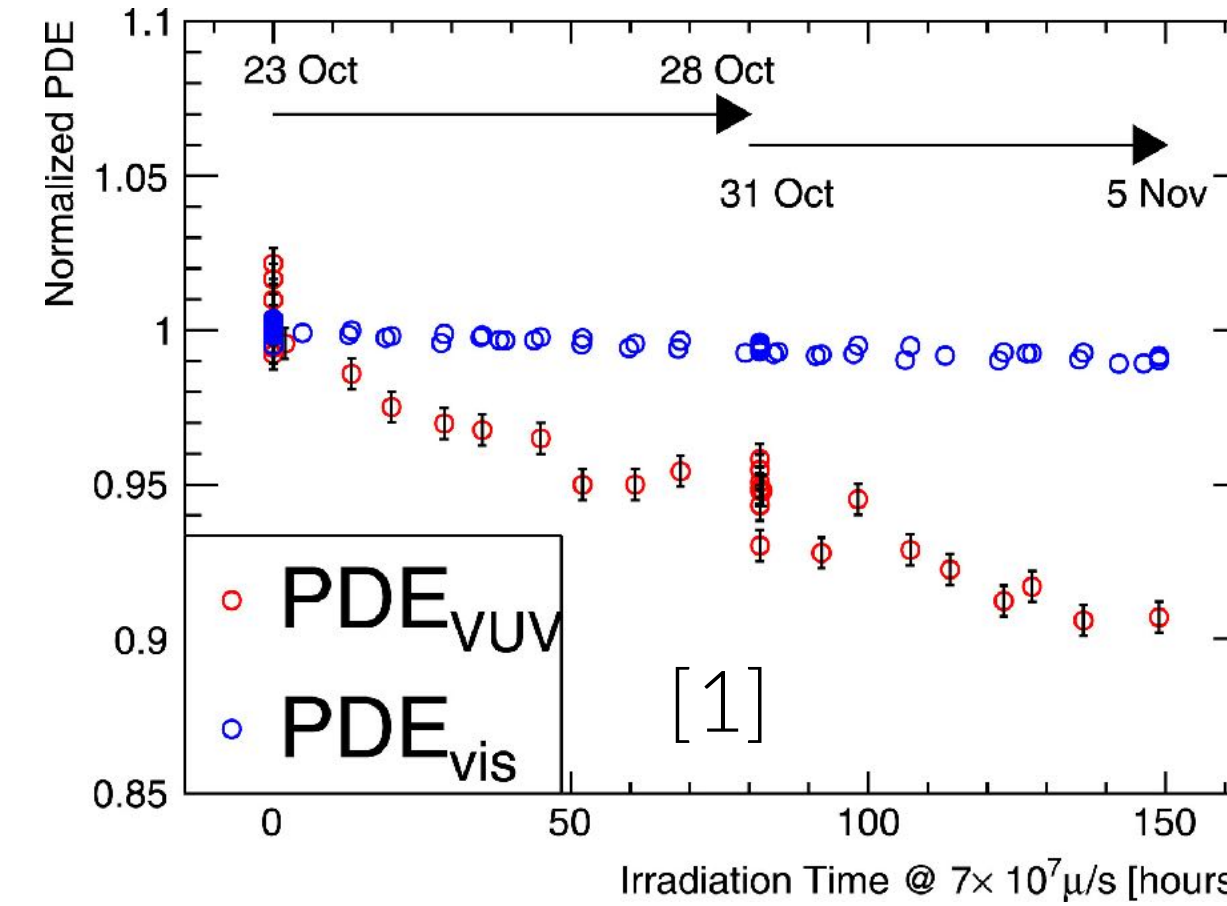
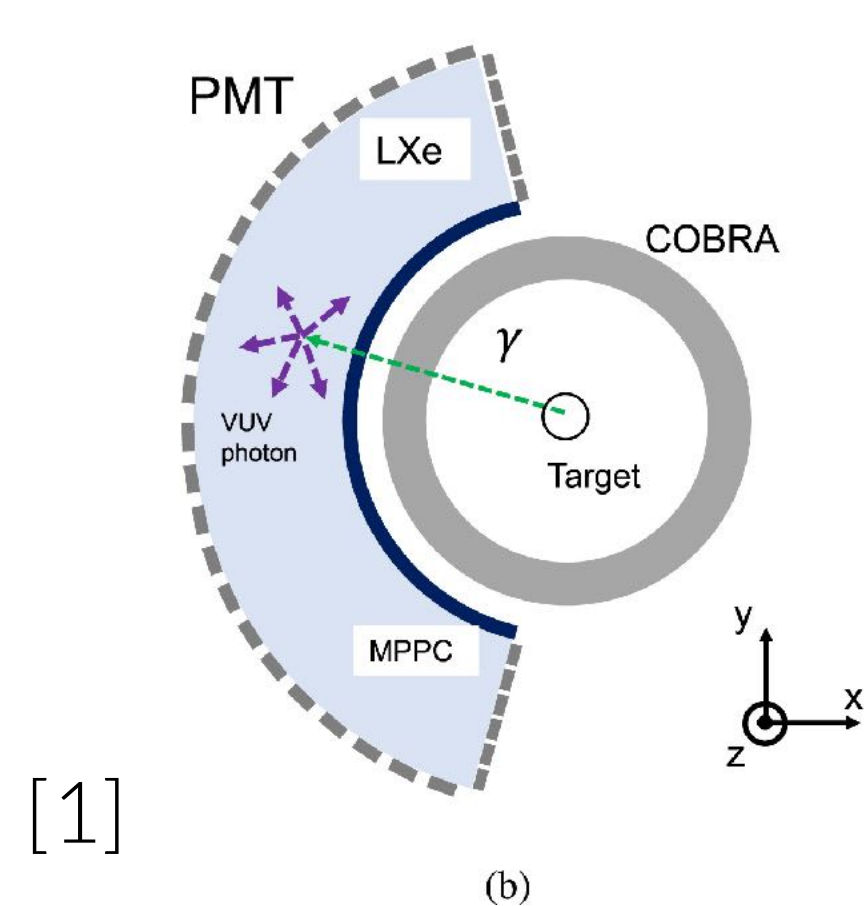
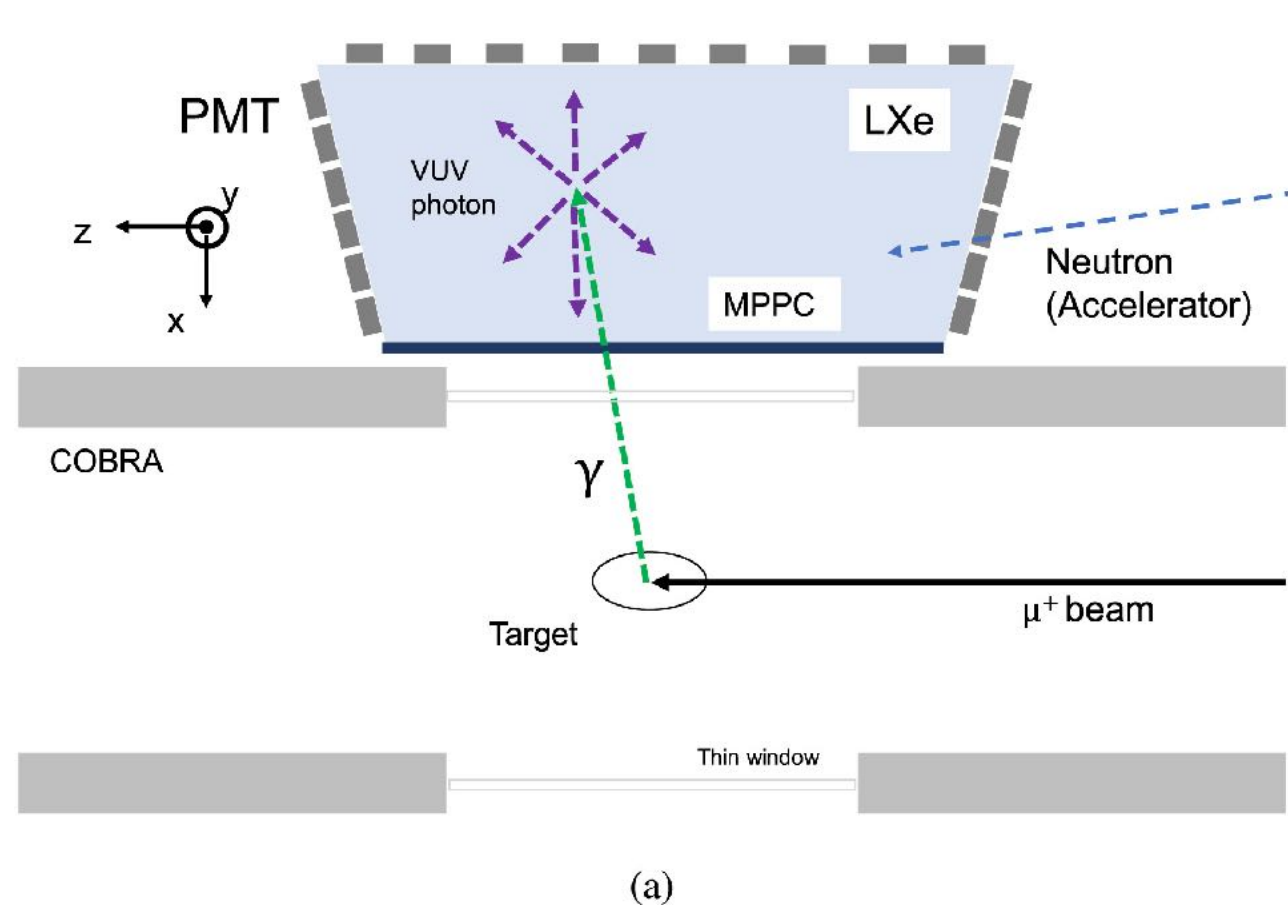
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Abstract

The VUV sensitivity of MPPCs deployed in the MEG II liquid xenon γ -ray detector has been observed to degrade under high-rate irradiation [1]. We conducted a VUV irradiation test of the MPPCs in LXe using α particles emitted from ^{241}Am , to identify the mechanism underlying VUV-sensitivity degradation. The two MPPC chips exposed to 10^{11} VUV photons show different trends in the number of photoelectrons, providing no conclusive evidence of VUV-sensitivity degradation. This poster also discusses ongoing and planned studies towards more conclusive testing.

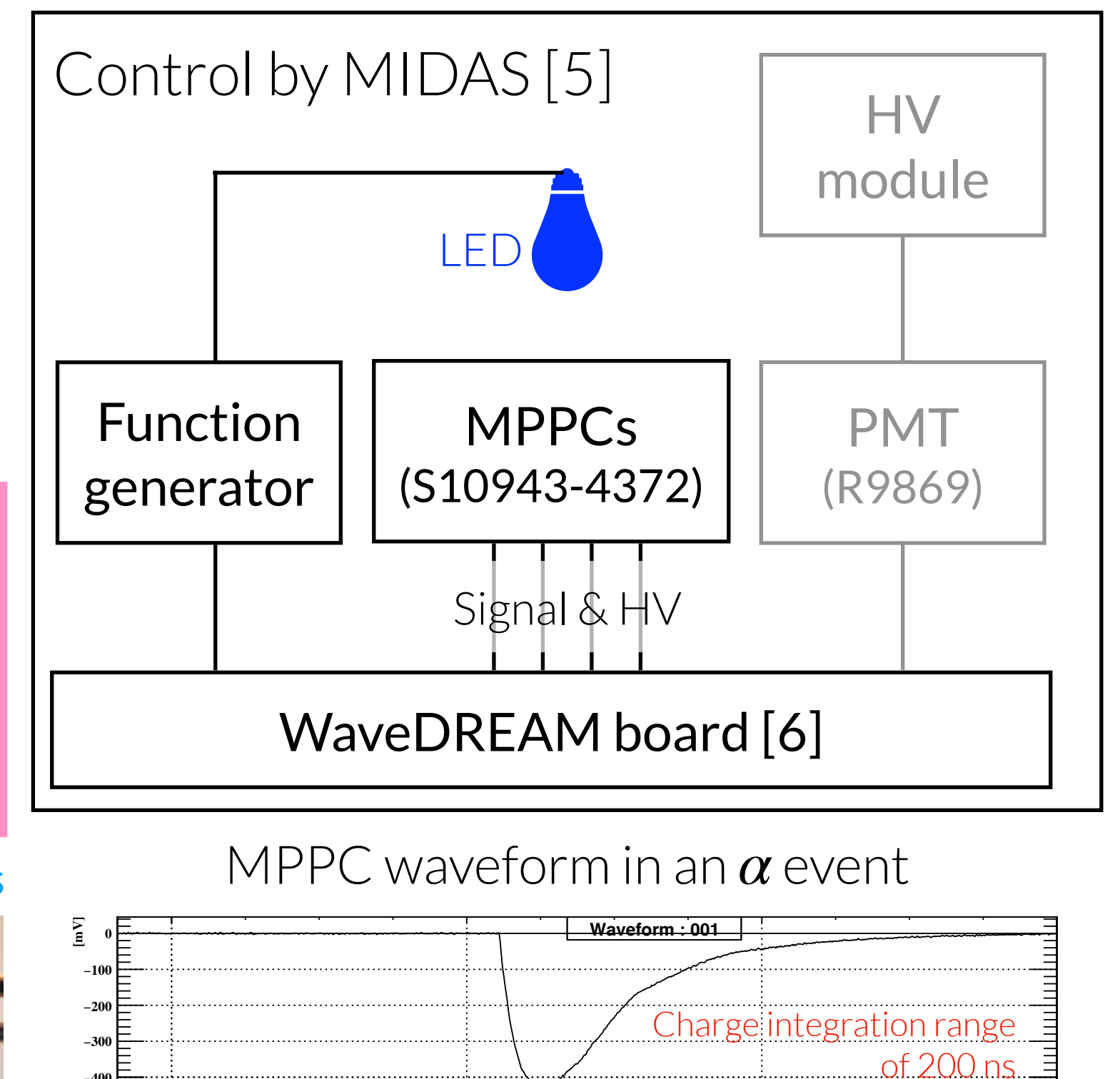
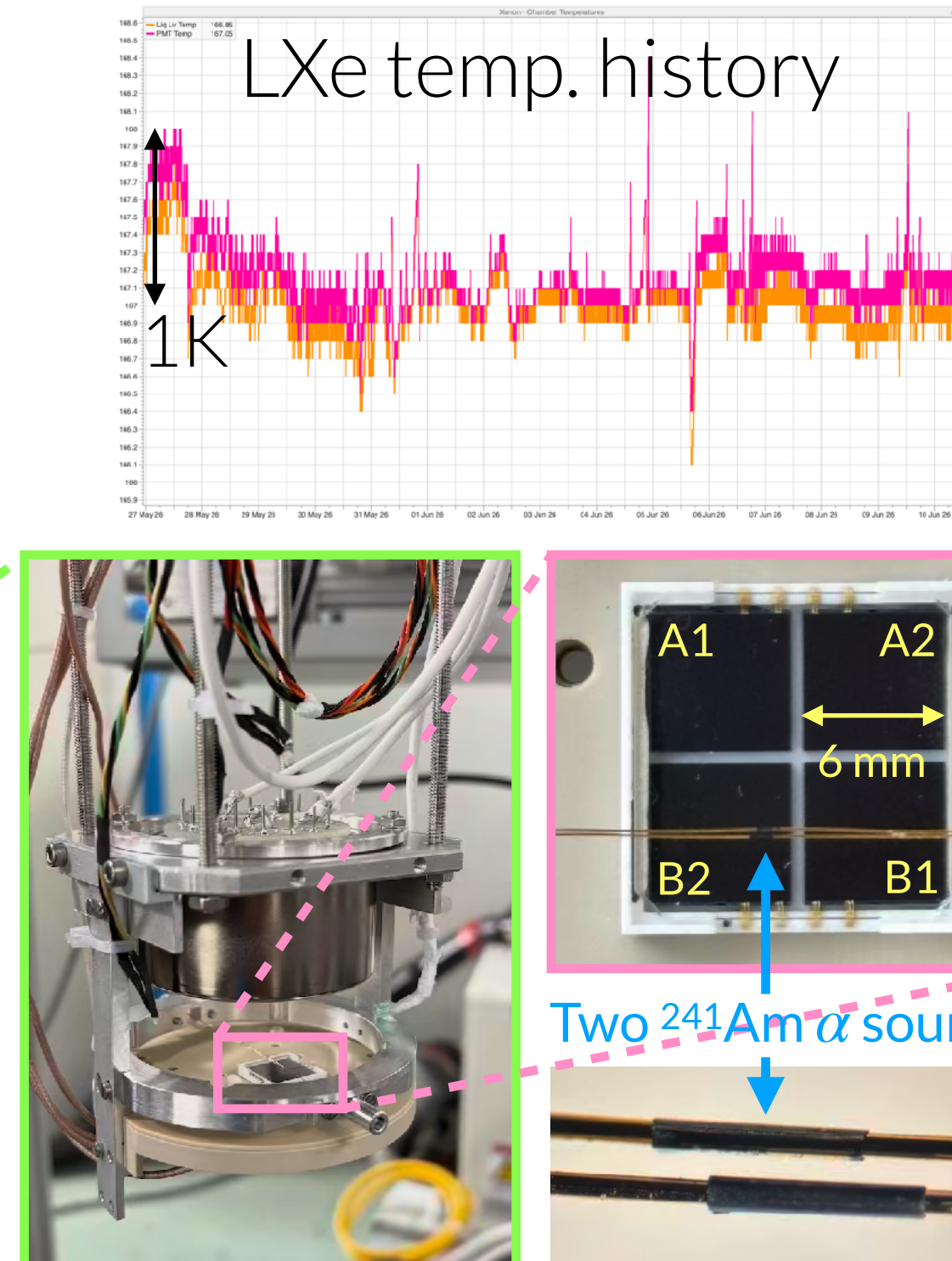
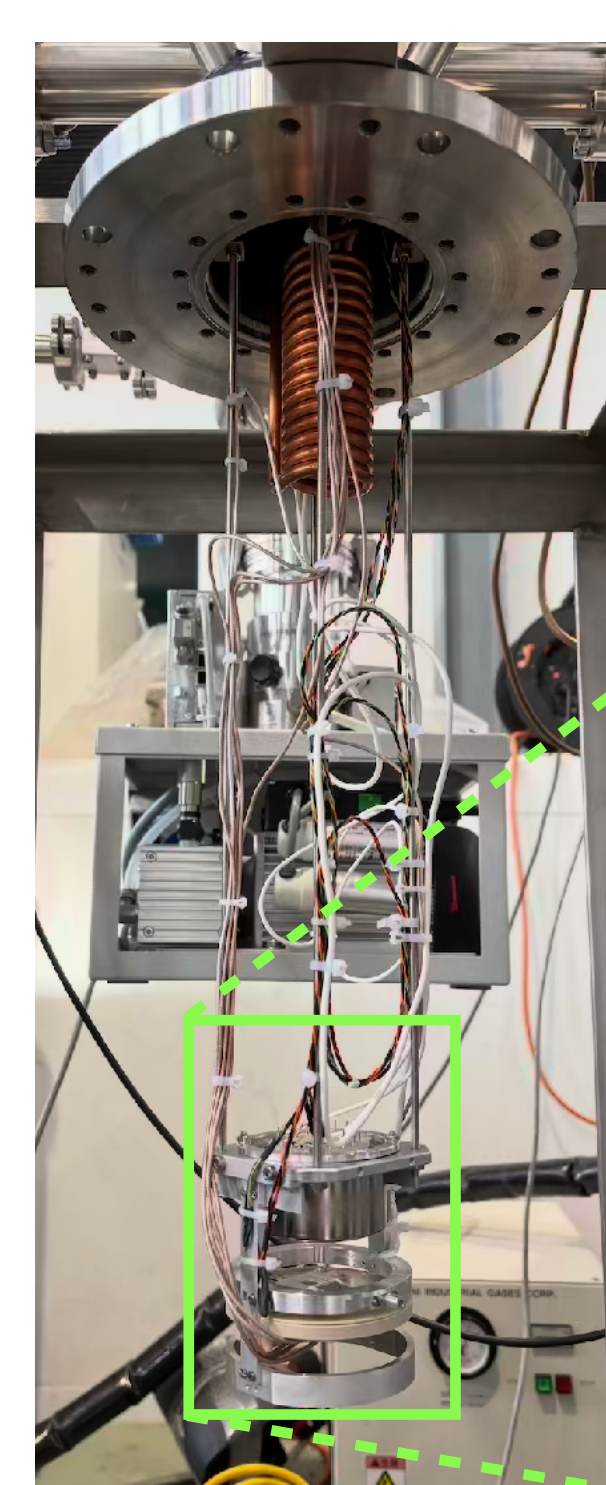
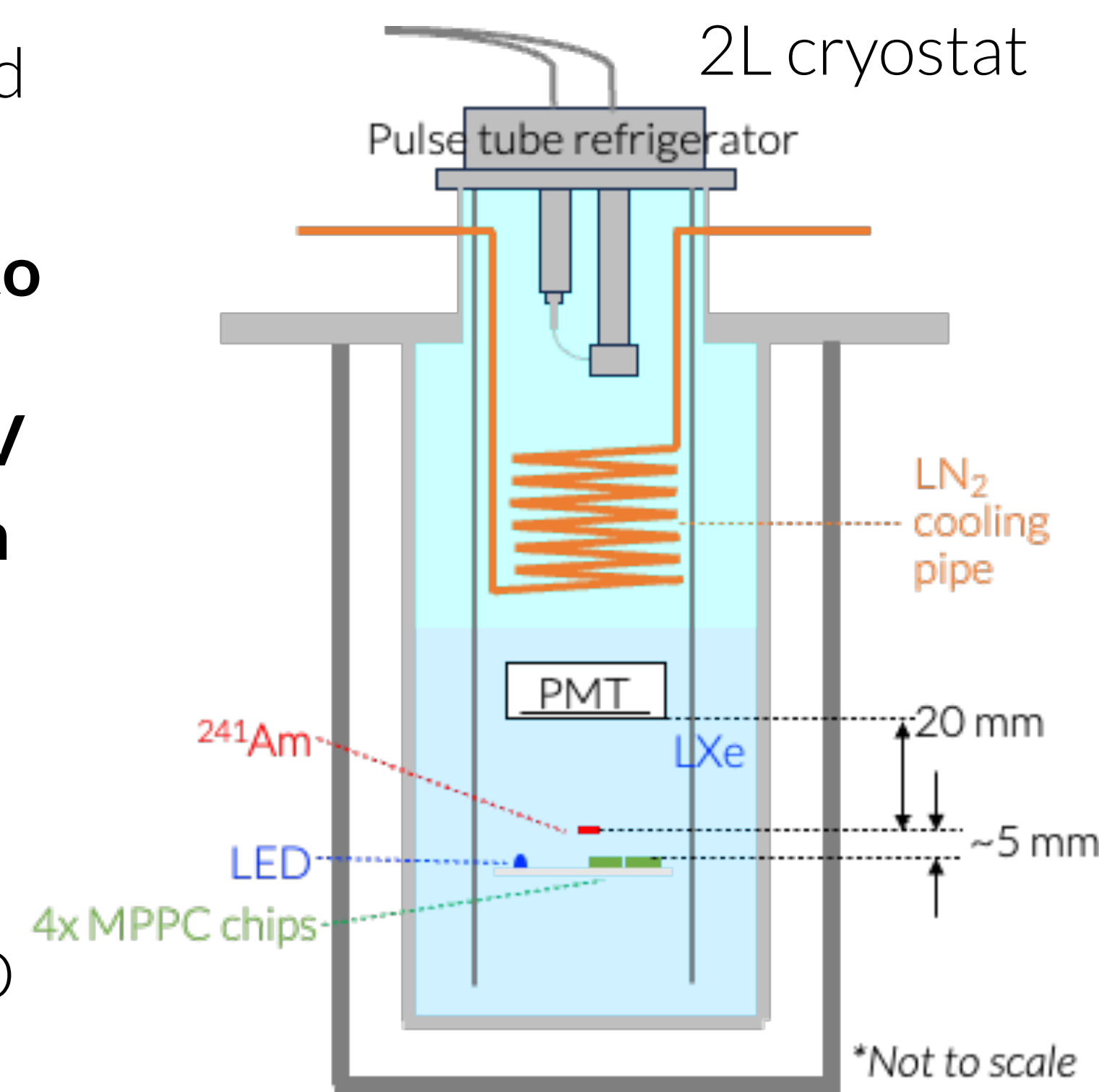
Motivation: To identify the mechanism of the VUV-sensitivity decrease observed in the MEG II experiment

- A liquid xenon γ detector using 900 L of LXe & 4760 VUV-sensitive photosensors has been developed in the MEG II experiment, in search of $\mu^+ \rightarrow e^+ \gamma$ [2, 3]
- 4092 newly developed MPPCs [4] are installed on the photon-incident surface
- Photon detection efficiency for VUV light has decreased as beam is irradiated**

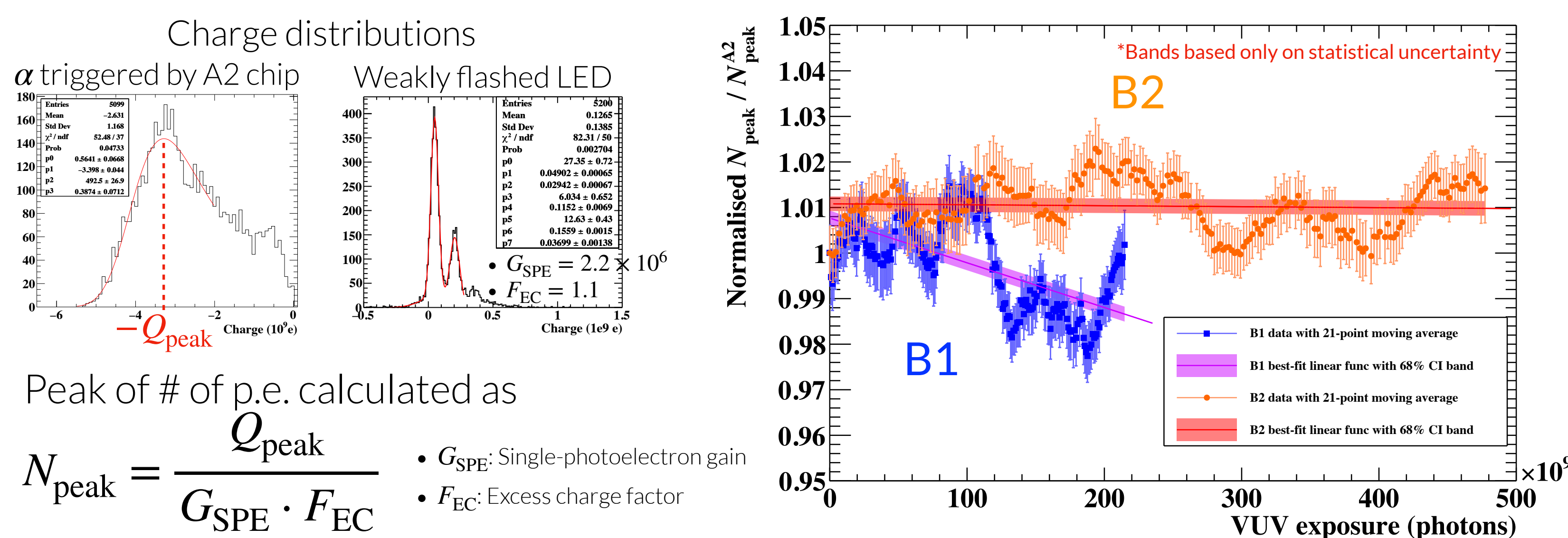


VUV irradiation test setup in LXe

- VUV photons suspected of "ionizing particle"
- MPPC chips exposed to LXe scintillation light (175 nm) from 5.5 MeV α particles from ^{241}Am**
- Exposure for 10 days
- With biasing
- Self-triggered α data and weakly flashed LED data acquired hourly



Results: Different behaviours between two MPPC chips



VUV flux estimated as $\Phi_{\text{VUV}} = (5 \pm 1) \times 10^5 \text{ s}^{-1}$ **Not conclusive due to different behaviours**

Consistent with two estimation methods:

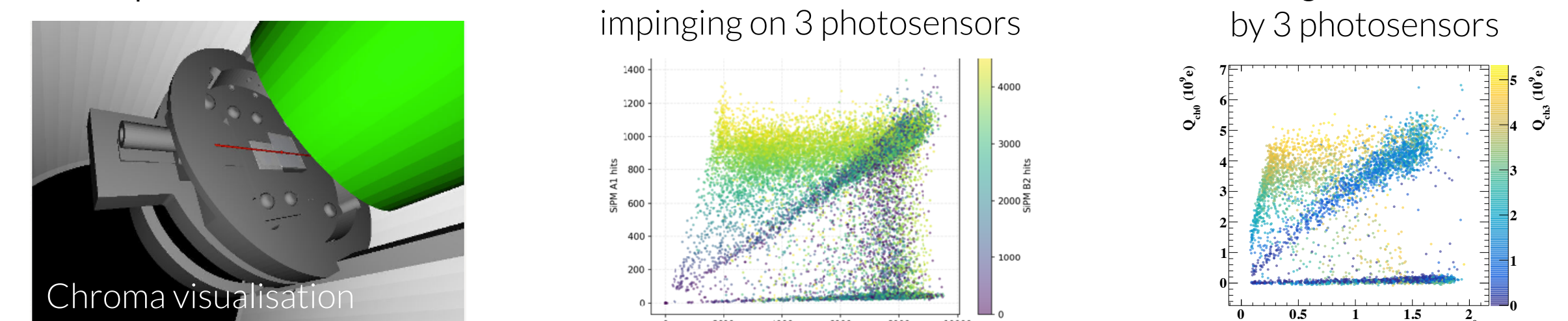
Trigger channel basis: $\Phi_{\text{VUV}} = \frac{\bar{N}}{\text{PDE}} \cdot R_{\text{TRG}}$

Current basis: $I \propto \Phi_{\text{VUV}} \cdot G_{\text{SPE}} \cdot F_{\text{EC}} \cdot \text{PDE}$

Dominant uncertainty on flux is **PDE** (25%)

Towards more conclusive testing

- Higher exposure** to see a more significant trend
- Planning positron beam test at PiM1 beamline at Paul Scherrer Institut (Switzerland) this autumn
 - Positron beam rate is 10^6 e/s , and expected VUV flux is 10^8 photons/s
- Precise PDE calculation** required to precisely calculate VUV photon flux
- Chroma [7] -based optical simulation in progress
 - To compare measured # of p.e. and simulated # of VUV photons



References

- [1] K. Ieki, et al., NIM-A 1053 (2023), 167365
- [2] A. M. Baldini, et al., EPJC 78 (2018), 380
- [3] K. Afanaciev, et al., EPJC 84 (2024), 190
- [4] K. Ieki, et al., NIM-A 925 (2019), 148-155
- [5] MIDAS, <https://daq00.triumf.ca/MidasWiki/>
- [6] L. Galli, et al., NIM-A 936 (2019), 399-400
- [7] Chroma, <https://github.com/pennneutrinos/chroma>

Acknowledgement

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Summary

- Conducted a VUV irradiation test in LXe on VUV-sensitive MPPCs to investigate the mechanism of VUV-sensitivity degradation observed in the MEG II LXe γ -ray detector
- Two MPPC chips exposed to 10^{11} photons show different trends in the number of p.e., giving no conclusive results on PDE degradation
- Plan a higher-irradiation test with a high-intensity positron beam at PSI